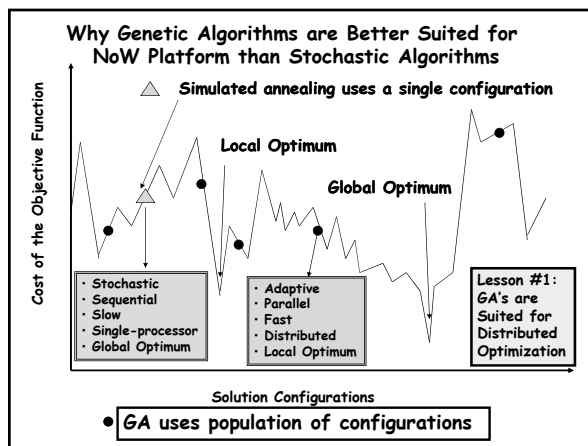
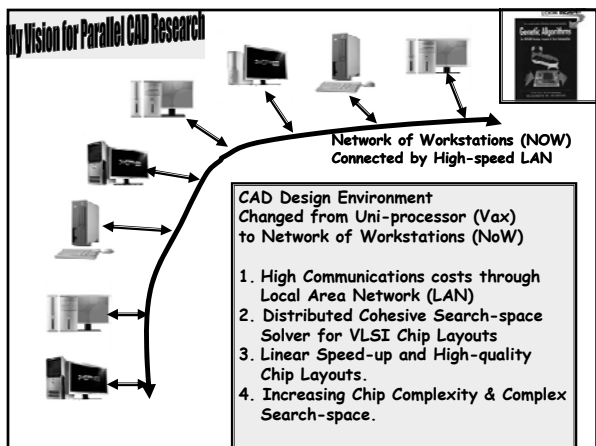
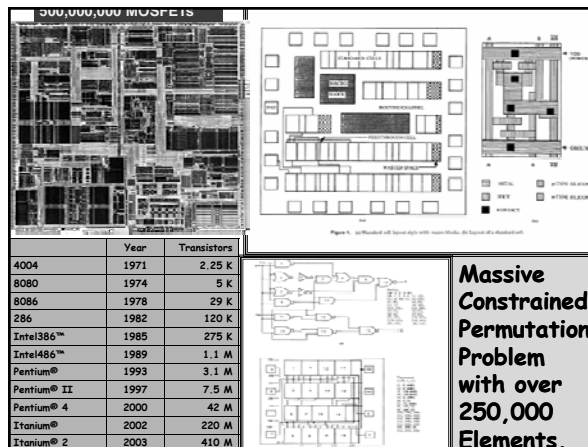
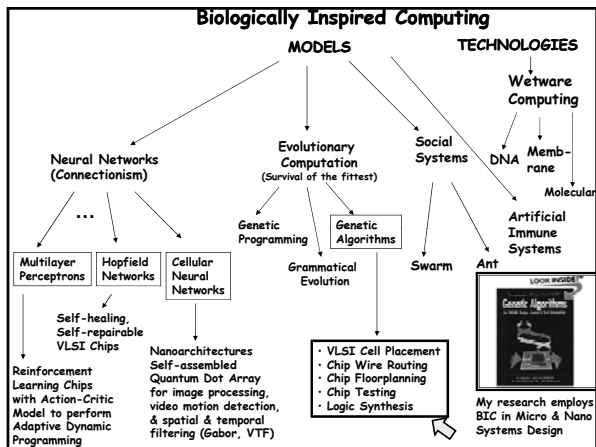


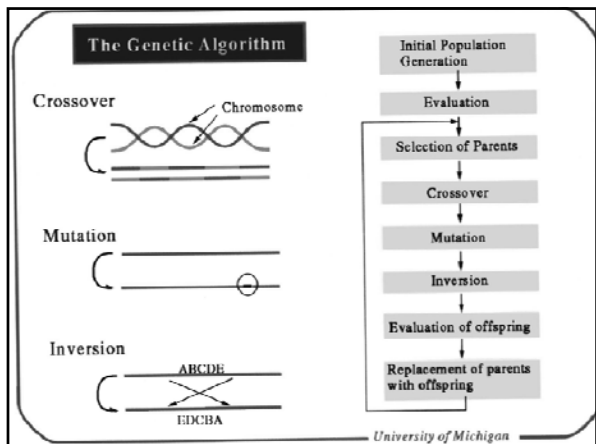
Biologically Inspired Algorithms for Micro and Nano System Design

Prof. Pinaki Mazumder,
Univ. of Michigan
Ann Arbor, MI 48105

Outline of the Talk

- Evolutionary Approach to Distributed VLSI Layout Synthesis
- Self-Healing of VLSI Chips by Neurally Inspired Hardware Methods
- Neuromorphic Nanoarchitecture using Cellular Nonlinear Network Model
- Reinforcement Learning Hardware



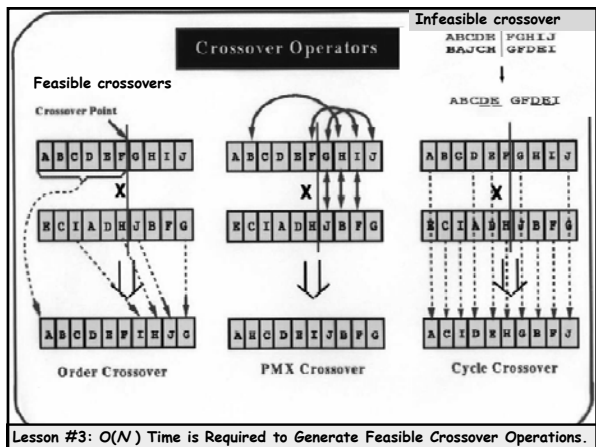


Meta-Optimization Algorithm

GA Parameters

Adjustments of crossover, inversion, mutation rates; population size; selection criteria

Lesson #2: GA's have Many Parameters Requiring a Meta Optimization Process



SA v. GA

Comparison with Simulated Annealing

Lesson #4: GA is Fast, but Tends to Optimize Locally for Problems with Very Large Search Space.

Macro Cell Placement - Genetic Encoding

Multi-Dimensional Search Space for Macro-Cell Placement with Translation, Mirroring, Rotation, etc. Operations.

- The algorithm is based on a generalization of the two-dimensional bin packing problem
- The search is restricted to the subset of placements in which no cell can be moved further left or down
- The genetic encoding of a macro cell placement automatically enforces the satisfaction of most constraints
- At any point in time each individual satisfies every constraint
- The layout quality obtained is comparable to the best known results

Lesson #5: GA is Effective for Many Real World Problems that Require MULTI-DIMENSIONAL CROSSOVER OPERATORS

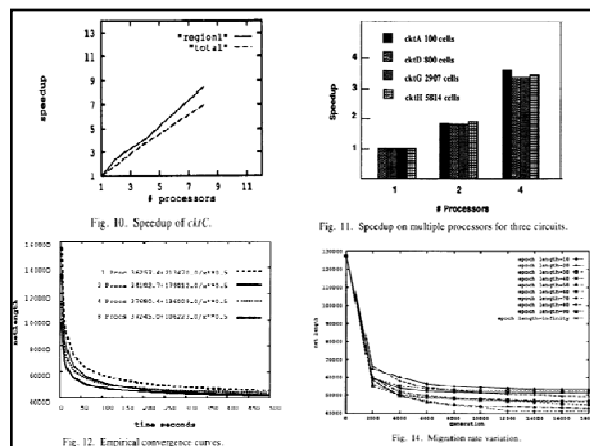
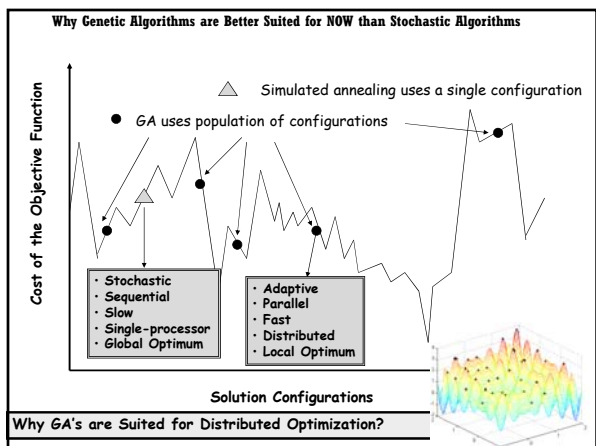
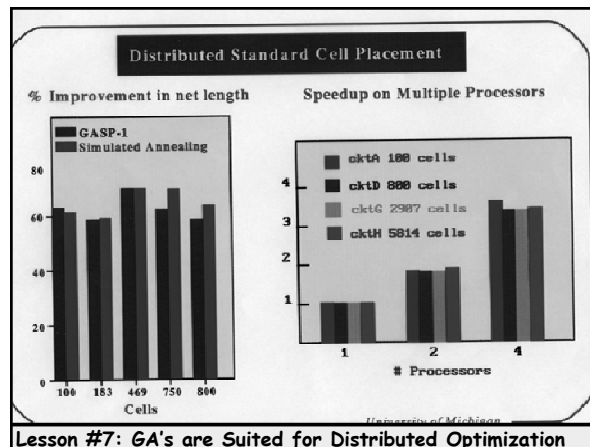
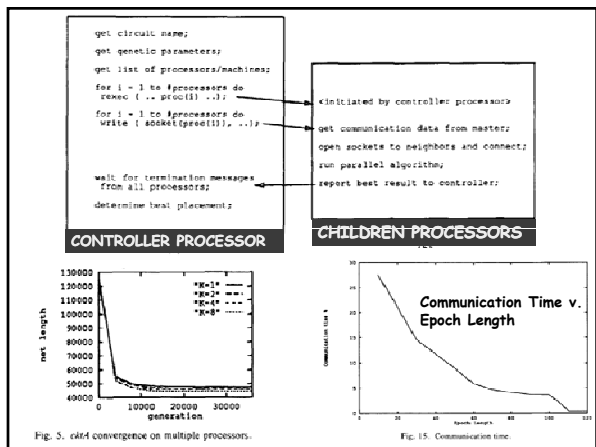
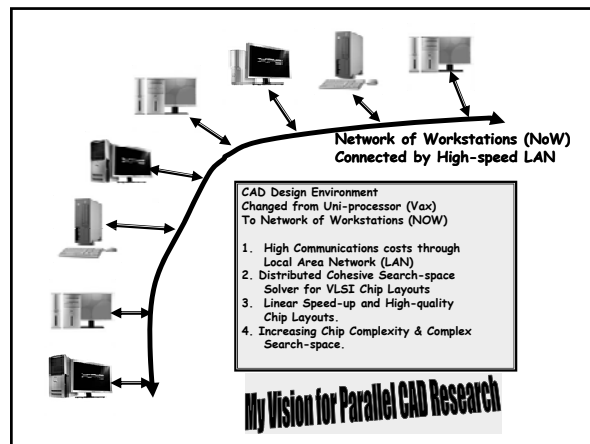
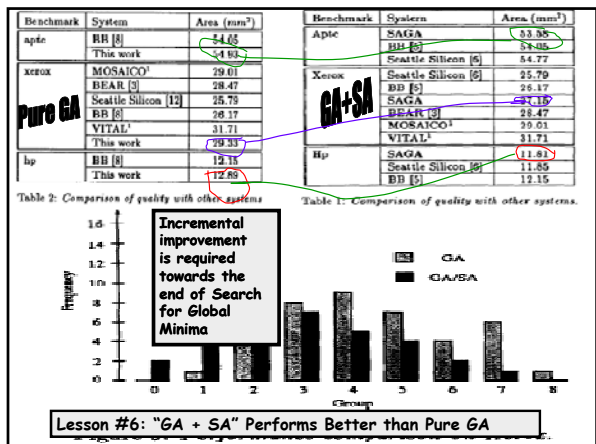
Figure 3: A genotype and the corresponding phenotype.

Figure 4: Combining α and β .

Figure 5: Placement result for the seven benchmarks.

Figure 4: Combining α and β .

Multiobjective Optimization Requires Multi-D Crossover

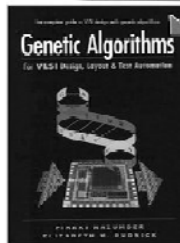


VARIOUS ASPECTS OF GA'S FOR VLSI DESIGN, TEST AND LAYOUT OPTIMIZATION

- Adaptive, learns from experience
- Intrinsic Parallelism
- Efficient for complex problems with hilly search spaces
- Can handle various cost functions and constraints
- Easy to parallelize on a workstation network, without much communication overhead, and with near-linear speedup

University of Michigan

LOOK INSIDE!



Opportunities for Future Research:

Mathematical Modeling of Genetic Process

Simulated annealing uses Markov Chain to give polynomial time solution.

Probability analysis & Empirical modeling is needed for sequential and distributed Genetic optimization.

Circuit partitioning
 Macro cell routing, including Steiner problems and global routing
 Standard cell and macro cell placement
 Circuit segmentation, FPGA mapping and pseudo-exhaustive testing
 Automatic test generation including compaction, deterministic/genetic test hybrids and integration of finite state machine sequences
 Peak power estimation

OPEN PROBLEM #1: Markov Chain can be used to model the Simulated Annealing by representing each solution configuration by a State in the Markov Chain and by using the probability of an Incremental transformation as the Transition Probability between different states.

It will lead to a Markov Chain of Length, L such that at the end one can obtain near Global Optimal solution. The Length, L can be controlled by selecting suitable Annealing Parameters and Inner Loop stopping criteria up to 4 or 5 Variables only.

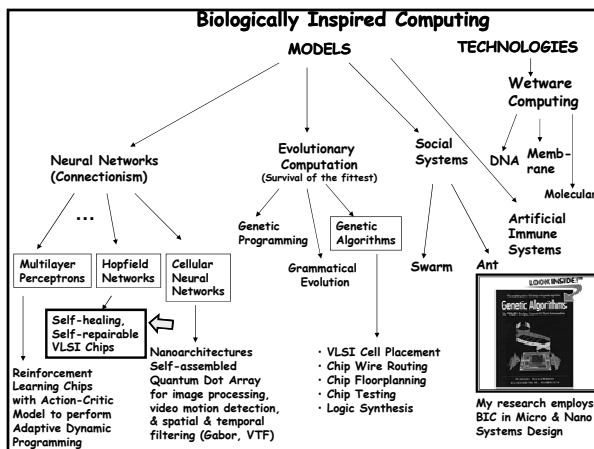
However, the Genetic Algorithm applies Crossover that Causes Multiple Changes in the Chromosome. It cannot be represented by the Markov Chain model. A better way to apply very rigorous Probability Modeling Technique that will simultaneously optimize parameters such as Crossover rate, Mutation rate, Inversion rate, Population Size, etc.

OPEN PROBLEM #2: Distributed Genetic Algorithm will require a more complex Mathematical Modeling to compute the Epoch rate, Search cohesion, Speedup, etc.

OPEN PROBLEM #3: Are GA's suited for Constrained Combinatorial Optimization like in VLSI layouts? How to devise clever Crossover Operators for such cases? Are there advantages of Multidimensional Crossover operators in Multivariate Optimizations?

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Neural Inspired Chip Healing

Objective of the Proposed R

- Adaptive Self-Testing
- Build-in Self-Repair
- Adaptive Self-Diagnose
- Design of Programmable Switching Circuits
- Design of Heuristic Repair Algorithms
- Design of Reconfiguration Circuits
- Development of Theory
- Development of Adaptive Circuits
- Circuit and Logic Simulation
- Fabrication and Testing

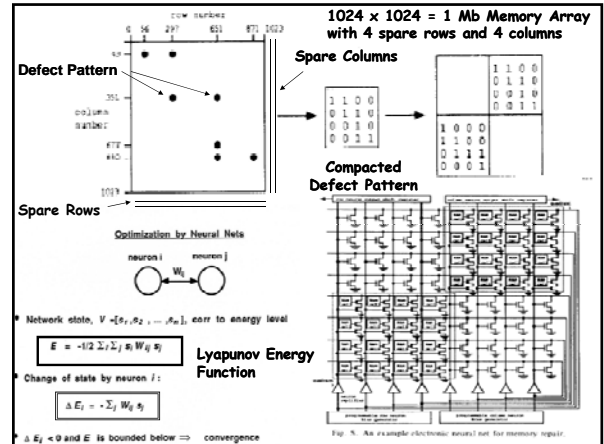
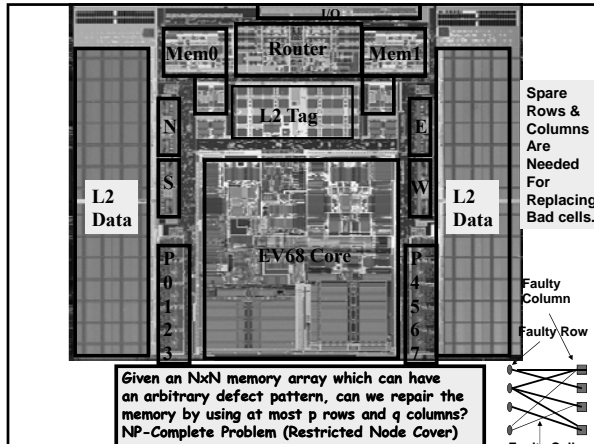
Circuits and Systems to Be Built:

Subcircuits: SFRAMs, PLAs, ROMs, Arithmetic and Logic Arrays
 Subsystems: Square Processor Arrays, Hex Mesh, Systolic Arrays
 Systems: MCMs, FCSs

Objective: Show the concept of self-healing by restructuring a megabit Memory array of RAM

Manufacturing Yield Reduces Dramatically As Chips Become Larger. Self Healing Is Needed to Improve Yield and Reduce Chip Manufacturing Cost.

Year	Transistors
4004	1971 2.25 K
8080	1974 5 K
8086	1978 29 K
286	1982 120 K
Intel386	1985 275 K
Intel486	1989 1.1 M
Pentium	1993 3.1 M
Itanium	2002 220 M
Itanium 2	2003 410 M



Cost of a Repair Scheme

- Spare Allocation Criteria**
 - To encourage all available spares be used
$$\Rightarrow C_1 = A/2 [(\sum s_{1i} - p)^2 + (\sum s_{2j} - q)^2]$$
- To encourage the min. usage of spares

$$\Rightarrow C'_1 = A/2 [(\sum s_{1i})^2 + (\sum s_{2j})^2]$$

- Fault Coverage Consideration**
 - To encourage all defects be covered
$$\Rightarrow C_2 = B [\sum_i \sum_j d_{ij} (1-s_{1i})(1-s_{2j})]$$

Cost Function $CMR = C_1 + C_2$ or $C'_1 + C_2$

Stochastic Gradient Neural Nets

Let $CMR = ENN$, we get

$$W_{1i, 1j} = -A(1-s_{1j}), \quad W_{2i, 2j} = -A(1-s_{2j})$$

$$W_{1i, 2j} = -B d_{ij}, \quad W_{2i, 1j} = -B d_{ij}$$

$$b_{1i} = (p - 1/2) A + B \sum_j d_{ij}$$

$$b_{2j} = (q - 1/2) A + B \sum_i d_{ij}$$

where $s_{ij} = 0$ if $i \neq j$, otherwise 1.

Hill Climbing Neural Nets

Let $CMR = ENN$ with self-feedback allowed, we get

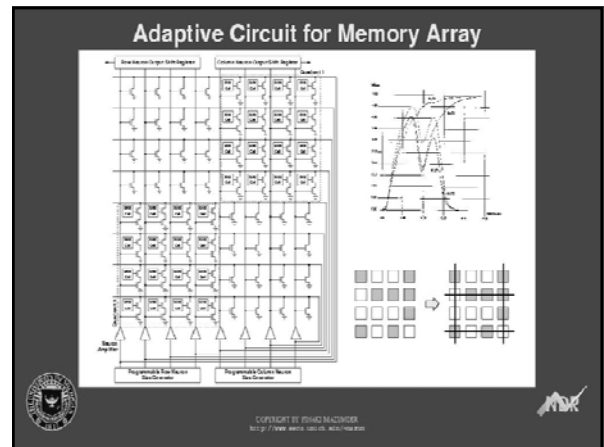
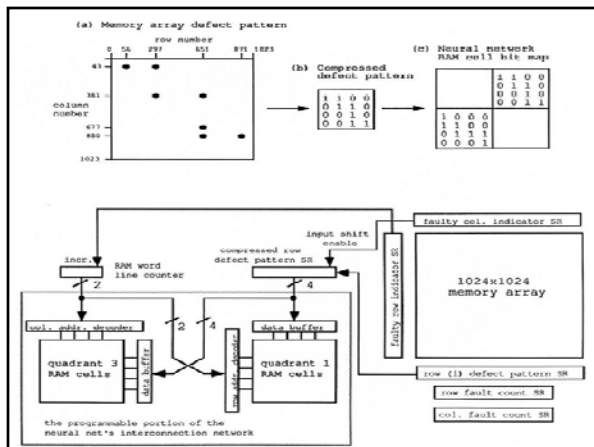
$$W_{1i, 1j} = -A, \quad W_{2i, 2j} = -A,$$

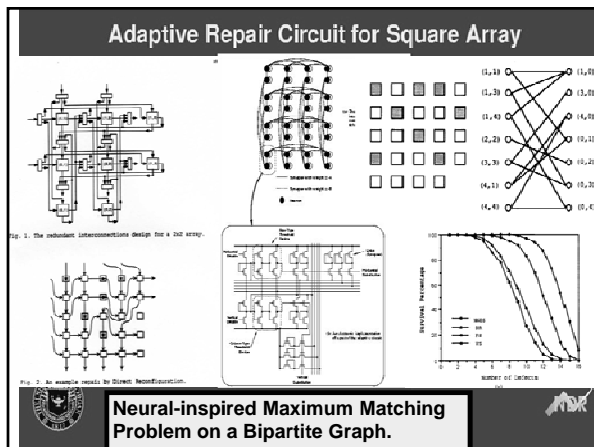
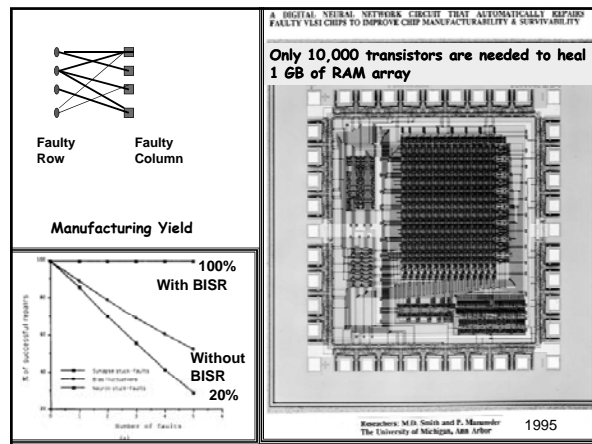
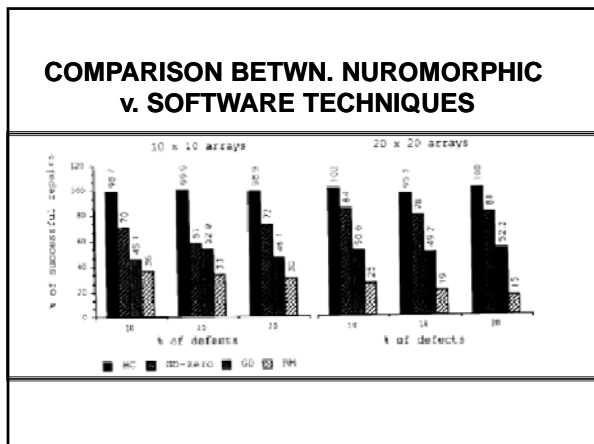
$$W_{1i, 2j} = -B d_{ij}, \quad W_{2i, 1j} = -B d_{ij}$$

$$b_{1i} = p A + B \sum_j d_{ij}$$

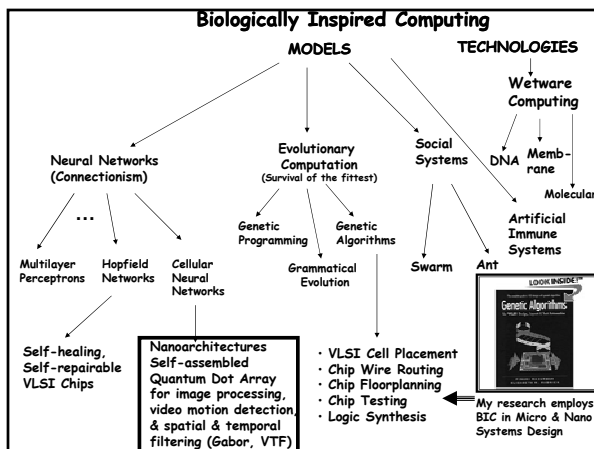
$$b_{2j} = q A + B \sum_i d_{ij}$$

Must have $A > B$





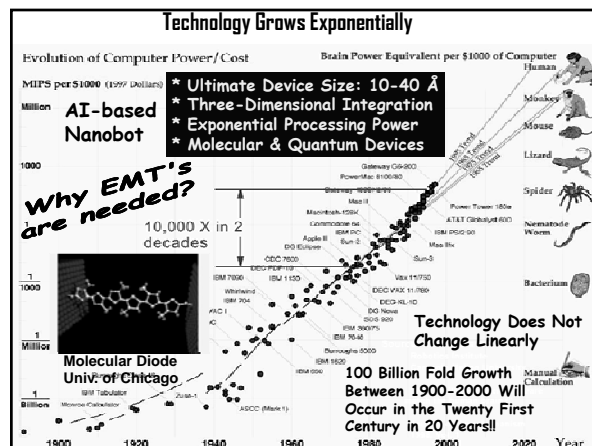
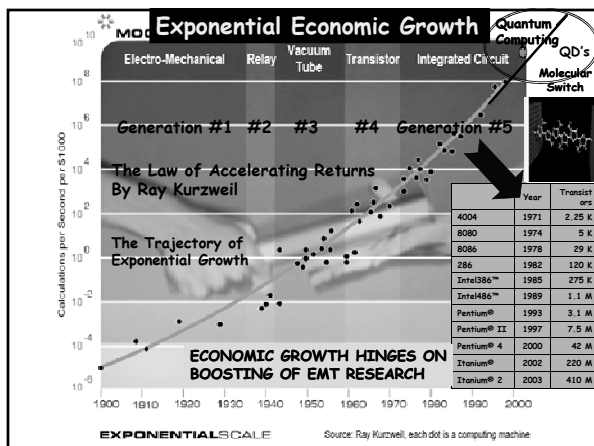
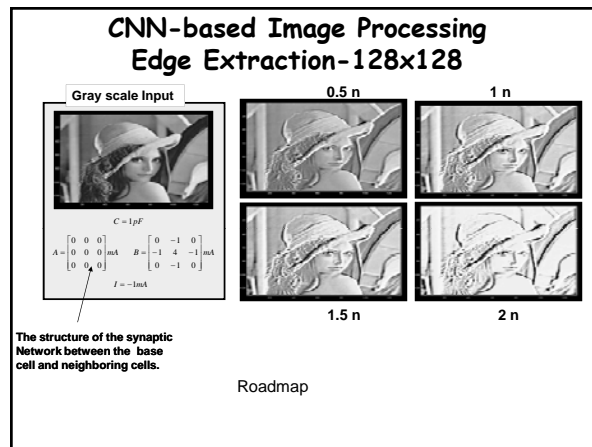
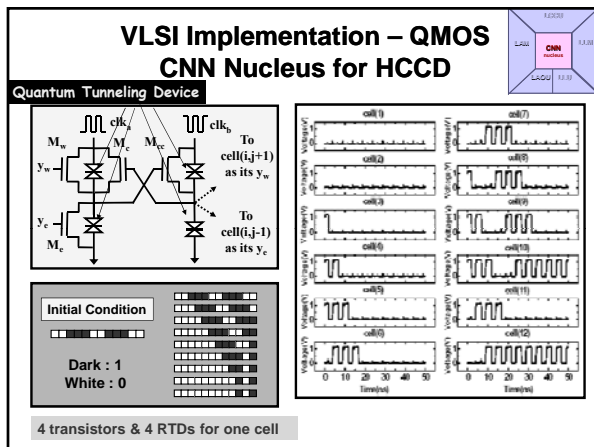
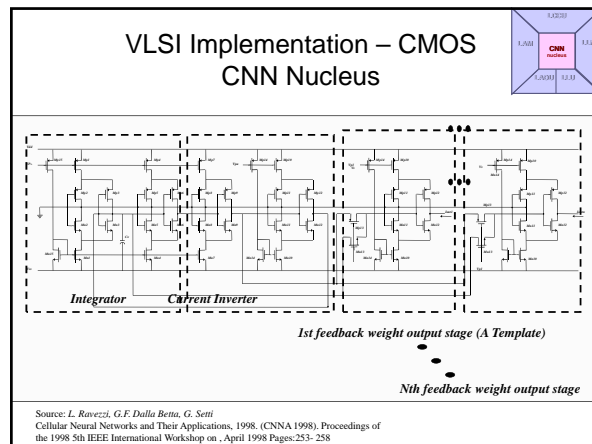
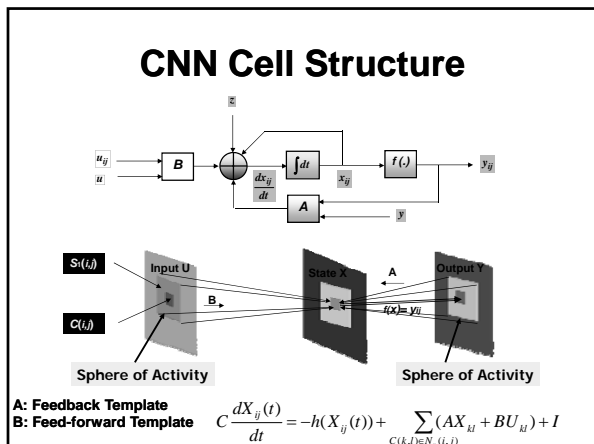
- ## Outline of the Talk
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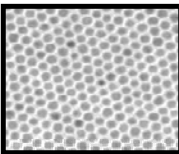
Emerging Research Architecture Implementations

QIS Perspectives: of ENT & ITIS Road Maps for Architectures are Consistent.

Architecture Implementations	Cellular Array Implementations	Digital Adherent Implementations	Stimulably Adaptive Implementations	Colony Quantum Computing
Quantum Cellular Automata	Cellular Nonlinear Networks	Reliable computing with unreliable devices (such as SETs with background noise)	Goal-driven computing using simple and recursive algorithms	Special algorithms such as factoring and deep data searches
• Not Universal	• Fast image processing • Associative memory • Complex signal processing	• Historical examples include VLSI • Ternary FPGA implementations	• High computational efficiency through data compression algorithms	QIS
Application Domains	• Arrays of molecules or molecular assemblies	• Resonant tunneling devices	• Molecular switches, • Crossed arrays of 1D structures	• Spin resonance transistors • NMR detectors • Single flux quantum devices • Photonics
Device And Interconnect Implementations	NANO		BIC	

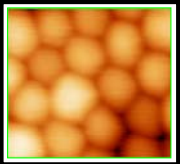


Nanoarchitectures with 0-D RTD & Self-Assembled Quantum Dots

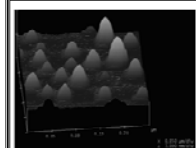


Scalability

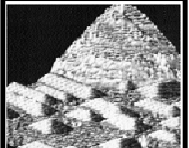
Quantum Dots Having 5 nm diameter



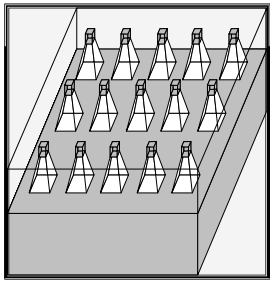
Self-assembled metal/molecule/metal nanostructures for nanoscale devices



Pyramidal Quantum Dots using GaAs



Quantum Dot Array



Quantum Dot Array

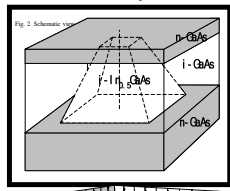
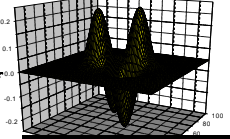


Fig. 2 Schematic view

D-CdS
i-In_{0.5}Ga_{0.5}As
In-CdS



2-D Wave Function With 21 meV Eigen Energy

```

graph TD
    Start([start]) --> Define[Define quantum dot structure]
    Define --> Save[Save mass (e and h), band alignment, doping distribution in files]
    Save --> Calc[Calculate 2D wave function in xy plane]
    Calc --> Solve[Solve 1D Schrodinger equation (in z direction)]
    Solve --> Boundary[Using boundary condition to get 3D S-Matrix]
    Boundary --> Integrate[Integrate T(E) over all possible energy]
    Integrate --> End([end])
            
```

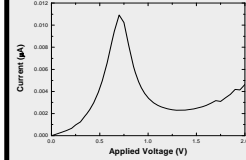
Multiscale Simulation: Quantum Device Modeling & Quantum Spice

$$\frac{\hbar^2}{2m^*} \left(\frac{\partial^2}{\partial x^2} + \frac{\partial^2}{\partial y^2} \right) \phi_r(x, y | z) + V_{LC}(x, y, z) \phi_r(x, y | z) = E_r \phi_r(x, y | z)$$

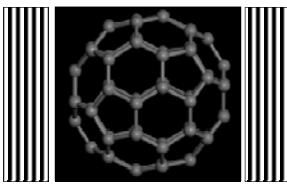
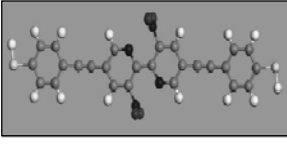
$$\frac{d^2}{dz^2} \chi_r(z) + k_r^2(z) \chi_r(z) = 0$$

$$\sum_r \left(2C_{rr}^{(0)}(z) \frac{d}{dz} \chi_r(z) + C_{rr}^{(0)}(z) \chi_r(z) \right) = 0$$

$$\Psi(x, y, z) = \sum_r \phi_r(x, y | z) \chi_r(z)$$

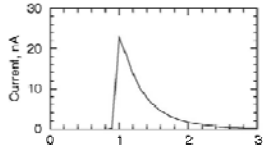
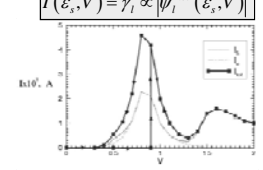
$$I_{tunnel} = \frac{e}{\pi \hbar} \int_{-\infty}^{\infty} T(E) [f_L(E) - f_R(E)] dE$$


Negative Differential Resistance of C60 & BPDN Molecules

bipyridyl-dinitro oligophenylene-ethylene dithiol (BPDN)

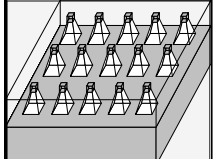
Tight-binding Hamiltonian model:

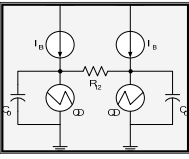
$$H = \sum \epsilon_0 (V_{tot}) c_i^+ c_i + hc_{i\pm 1}^+ c_i$$



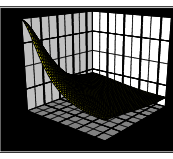
$$I(\epsilon_s, V) = \gamma_i \propto |\psi_i^{mol}(\epsilon_s, V)|^2$$

Courtesy: I. I. Oleynik & M. A. Kozhushner

Quantum Dot Array








$$V(z_m, z_n) = Z\text{-transform of a QD pair} = \frac{I'R_2}{2[1 - \cos(2\pi f_m)] + 2[1 - \cos(2\pi f_n)] + \alpha}$$


Connecting Resistance Defines the Mutual Voltage between a pair of QD's

Nanoscale Nonlinear Circuit Theory


Edge Detection by QDA



0 ns




1 ns




2 ns


Gray → Binary Conversion


Vertical Line Detection (VLD)



0 ns







6 ns

Image Processor is being fabricated and tested under a NIIRT project

VCU Circuit parameters based on measured values

- Single dot: $R_{inter\ dot} = 640\ M\Omega$
- Single dot: $C_{gate\ dot} = 5\ aF$
- Single dot: $C_{substrate} = 0.5\ aF$
- Single dot: Peak current = **15 pA**
- Superdot (1 pixel = 6400 dots): $R_{inter\ superdot} = 8\ M\Omega$
- Superdot: $C_{gate\ superdot} = 4\ fF$
- Superdot: $C_{substrate} = 0.2\ fF$
- Superdot: Peak current = $0.1\ \mu A$

Quantum Device Laboratory 2002,2003 page 29

Nanoarchitecture for Motion Estimation

Quantum Dot based Cellular Nonlinear Network with Motion Estimation Capability

Quantum Dots are underneath the top metal particles

$$H = \frac{1}{1 + 2\pi^2(a_E + b_W)f_x^2 + 2\pi^2(a_S + b_N)f_y^2 + j2\pi((a_x - b_x)f_x + (a_y - b_y)f_y + cf_t)}$$

$a_E + b_W = a_S + b_N > 0$; and $C > 0$.

$a = r/R, b = r/R, c = r/R, d = r/R, e = r/R, f = r/R$

HSPICE Result of QD VTF for $v = 0$

To get filtered output, S value should be above 1.45 for high valts $0.75\ (RTD\ mid\ voltage) + 0.7\ (diode\ threshold\ voltage)$

V = +2 pixel/sec
V = +1 pixel/sec
V = 0 pixel/sec
V = -1 pixel/sec
V = -2 pixel/sec

Input Images Filtered Output

3-D Self-Assembled Architectures

Yeh et al., IEEE Trans. on Nanotechnology, 6(2):109, 2007

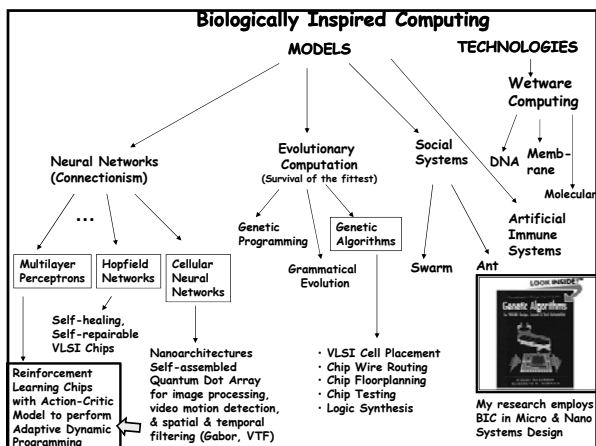
Raenssler Polytechnique Inst Los Alamos National Laboratory

Applications of 3-D Self-Assembled Architectures (Random Boolean Networks)


- Genetic Regulatory Networks (Kauffman 1993, Gershenson 2005)
 - Understanding of disease treatment
 - Genomic interaction and data mining
- Evolutionary Computing & Evolvable Hardware (JPL)
- Artificial Neural Networks (Huepe & Aldana, 2002)
- Social Modeling (Shelling 1971)
- Robotics (Quick, et al. 2003)
- Cellular Automata (Wuensche and Lesser, 1992)
- Percolation Theory (Stauffer, 1985)
- Biologically Inspired Computing (Swarm, Ant forage, ...)

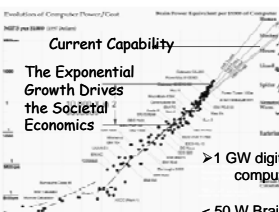
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The Holy Grail of Computing -- Can we spill human brain on Silicon?





Current Capability

The Exponential Growth Drives the Societal Economics

>1 GW digital computer

< 50 W Brain

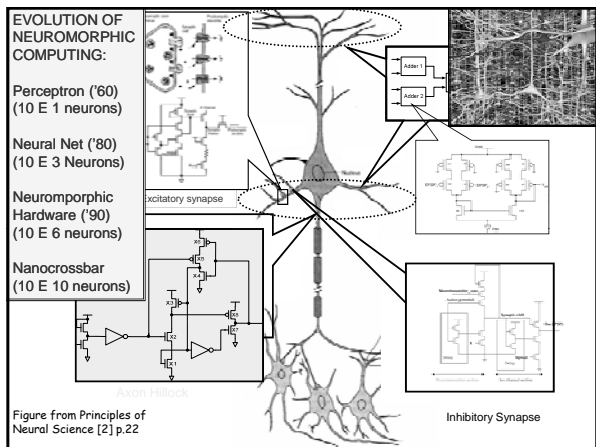
Facets of Neuromorphic or Brain-like Computing:

Self-Healing (Robust)

Cognition (Visual, Auditory, Tactile)


Spike Learning

Huge Memory

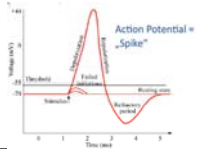


Biological Neuron Model

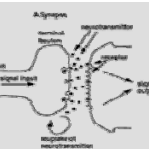
Ionic Transport in Biological Neuron & its Silicon Implementation



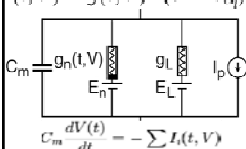
Hodgkin-Huxley Model



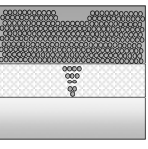
Action Potential = "Spike"

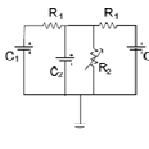


$$I(t, V) = g(t, V) \cdot (V - V_{r,q})$$



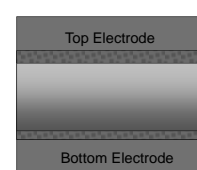
$$C_m \frac{dV(t)}{dt} = - \sum I_i(t, V)$$





Analog a-Si Memristors

- Uniform motion of the conducting front - analog switching (memristor)
- Creation of uniform conducting front by co-sputtering of a-Si & metal



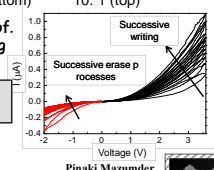
DARPA SYNAPSE PROJECT WITH HRL LABORATORIES

sputtered a-Si only co-sputtered Si & Ag (~20nm) mixture ratio (rough # of atoms), gradual change

Si & Ag only (bottom) 10:1 (top)

All Credits Go to Prof. Wei Lu's Outstanding Research Group

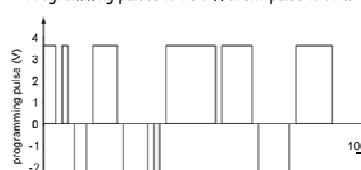
- Incremental conductance change
- Conductance \propto total charge through the device
- Highest process temperature < 260°C



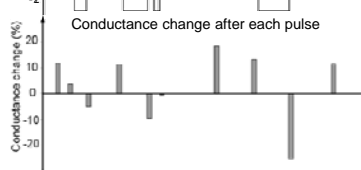
Pinaki Mazumder U of Michigan - NDR Group

Memristor: A New Paradigm Circuit Design

Programming pulses with different pulse widths



Conductance change after each pulse



Conductance controlled by the pulse width, and can be changed incrementally.

- Digitally Controlled
- Constant Amplitude
- Temporal Correlation

Neuron Spiking Signals and STDP Control

Hebbian-Type STDP Learning Model

Neurons that "FIRE" together, also "WIRE" together. - D. Hebb

$$\frac{d}{dt} w_{ij}^{LTP} = \gamma^{LTP} d_a \exp\left[-\frac{t-t_{pre}}{\tau_a}\right] \times d_b \exp\left[-\frac{t-t_{post}}{\tau_b}\right]$$

$$\times u(t-t_{pre})u(t-t_{post}) \Rightarrow w_{ij}^{LTP} \uparrow \text{ if } |t_{pre} - t_{post}| \downarrow$$

- Time Division Multiplexing
 - Events occur at proper timeslots
 - Long Term Potentiation can only occur in the 2nd timeslot
 - Long Term Depression can only occur in the 1st timeslot
 - Inputs are considered only in the 0th timeslot
- Each pulse of amplitude V is not enough to make a significant change to memristance
- When there's a net difference with amplitude 2V, memristance changes

Neuron spikes in first frame

SPDT with Memristor

Pulse Width vs. Pre and Post Neuron Spike Times

STDP obtained using memristor synapse

Neuron Pulse Width Curves (across a synapse)

For LTP case: The Post neuron is at -V while the Pre neuron at +V
 For LTD case: The Pre neuron is at -V while the Post neuron at +V
 LTP case is taken as positive while the LTD case negative

STDP-Based Position Detector

VERILOG SIMULATION

Position Detector

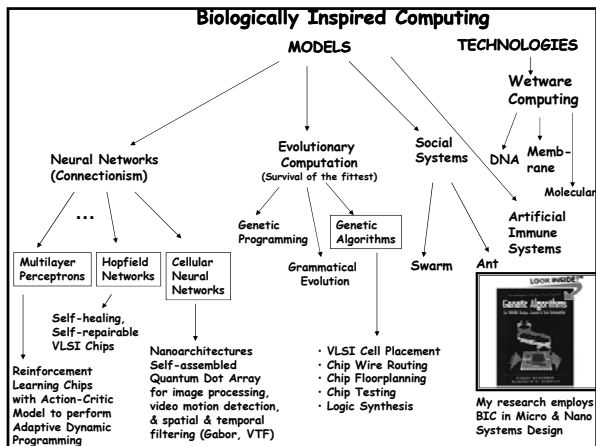
VERILOG SIMULATION

STDP Neural Circuit for Position Detector

Bases	Memristor Design	CMOS Design
Synaptic area	< (0.5μm x 0.5μm)	17μm x 16μm
Synaptic Density	> 4 devices/μm ² x1000	0.0037 devices/μm ²
Neuron area	20μm x 10μm	8μm x 12μm
Neuron Density	0.005 devices/μm ² x2	0.0104 devices/μm ²
Volatility	Nonvolatile	Volatile

STDP Based Position Detector

VERILOG SIMULATION



Evolutionary Computing plays a critical role in Layout Synthesis and Testing of VLSI Chips.

Neural Inspired Self-Healing plays a critical role in improving manufacturing yield and Survivability of chips.

Cellular Nonlinear Networks provide architectures for Nanoelectronics.

Learning-based VLSI chips will require major innovations in nanoelectronics from materials to architectures

THE END

My research group is also working on THz Sensing of DNA, RNA and Other Biomolecules